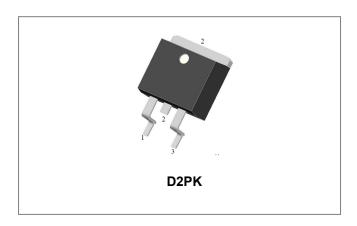






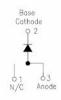
## 25TQ015S SCHOTTKY RECTIFIER



#### **Features**

- 100 °C T<sub>J</sub> operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced
- mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- · Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- · Additional testing can be offered upon request

### **Circuit Diagram**



### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

### Maximum Ratings@Tc=25°C unless otherwise specified

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ \end{array}$	-	15	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=90°C, rectangular wave form	25	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse	150	A

### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop *	V <sub>F1</sub>	@ 25A, Pulse, T <sub>J</sub> = 25 °C	0.37	0.45	V
Reverse Current *	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ $T_J = 25  ^{\circ}\text{C}$	4	15	mA
Junction Capacitance	Ст	$@V_R = 5V, T_J = 25 °C$ $f_{SIG} = 1MHz$	1270	2500	pF
Series Inductance	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

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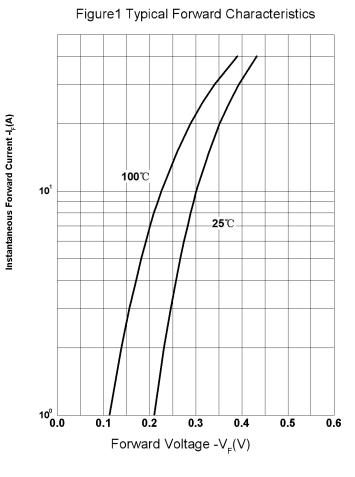


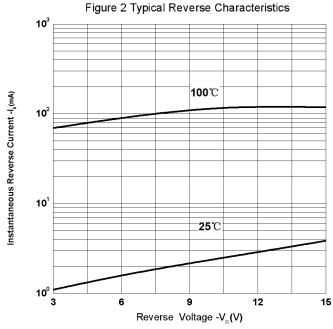


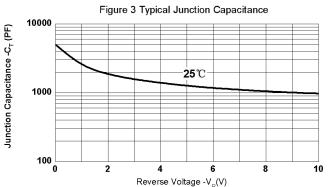
## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +100	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +100	°C
Typical Thermal Resistance Junction to Case	Rejc	DC operation	0.8	°C/W
Approximate Weight	wt	-	1.85	g
Case Style	D <sup>2</sup> PAK			

## **Ratings and Characteristics Curves**







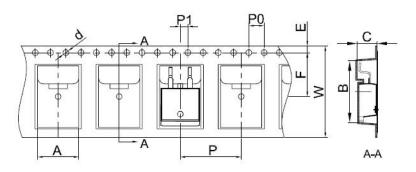
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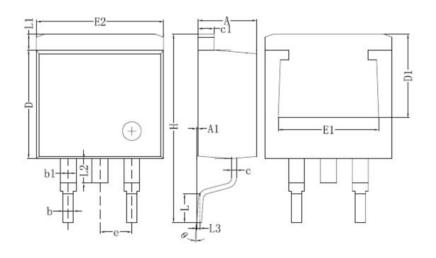


# Carrier Tape Specification D<sup>2</sup>PAK



Symbol	Millimeters		
Зуппоот	Min.	Max.	
A	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

## Mechanical Dimensions D<sup>2</sup>PAK



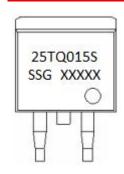
Symbol	Dimensions in millimeters		
Symbol	Min.	Max.	
Α	4.06	4.83	
A1	0	0.26	
b	0.51	0.99	
b1	1.14	1.78	
С	0.31	0.74	
c1	1.14	1.65	
D	8.38	9.65	
D1	6.4		
E1	6.22		
E2	9.65	10.67	
е	2.54BSC		
Н	14.6	15.88	
L	1.78	2.8	
L1	-	1.68	
L2	-	2.2	
L3	0.255BSC		
Θ	0	8°	

## **Ordering Information**

Device	Package	Shipping
25TQ015S	D <sup>2</sup> PAK (Pb-Free)	800 pcs/ reel
25TQ015STR	D <sup>2</sup> PAK (Pb-Free)	800 pcs/ reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**



### Where XXXXX is YYWWL

25 = Forward Current (25A)
TQ = Device Type
015 = Reverse Voltage (15V)
S = Package type
SSG = SSG

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

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